

2 μ A, 600mA Low Dropout Voltage Linear Regulator

General Description

The RS1562N series are a group of low-dropout (LDO) voltage regulators offering the benefits of wide input voltage range from 1.2V to 5.5V, low dropout voltage, low power consumption, and miniaturized packaging.

Quiescent current of only 2 μ A makes these devices ideal for powering the battery-powered, always-on systems that require very little idle-state power dissipation to a longer service life. There is an option of shutdown mode by selecting the parts with the EN pin and pulling it low. The shutdown current in this mode goes down to only 10nA (typical).

The RS1562N series of linear regulators are stable with the ceramic output capacitor over its wide input range from 1.2V to 5.5V and the entire range of output load current (0mA to 600mA).

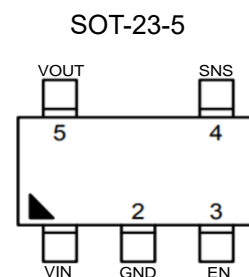
Features

- 2 μ A Ground Current at no Load
- \pm 2% Output Accuracy
- 600mA Output Current
- 10nA Disable Current (by option)
- Wide Operating Input Voltage Range: 1.2V to 5.5V
- Dropout Voltage: 0.32V at 600mA / V_{OUT} 3.3V
- Adjustable Output Voltage Available by Specific Application
- Stable with Ceramic or Tantalum Capacitor
- Current Limit Protection
- Over-Temperature Protection
- SOT-23-5 Packages Available

Applications

- Portable, Battery Powered Equipment
- Low Power Microcontrollers
- Laptop, Palmtops and PDAs
- Wireless Communication Equipment
- Audio/Video Equipment
- Car Navigation Systems

Pin Configurations



Ordering Information

RS1562N-**AA****BB**

Designator	Description	Symbol	Description
AA	Reference Voltage (SNS Pin)	12	$V_{OUT} = 1.2V$
BB	Package type	S5	SOT-23-5

Description of Functional Pins

RS1562N

Pin No	Pin Name	Pin Function
SOT-23-5		
1	VIN	Input of Supply Voltage.
2	GND	Ground
3	EN	Enable Control Input.
4	SNS	Sense of Output Voltage.
5	VOUT	Output of the Regulator

Typical Application Circuit

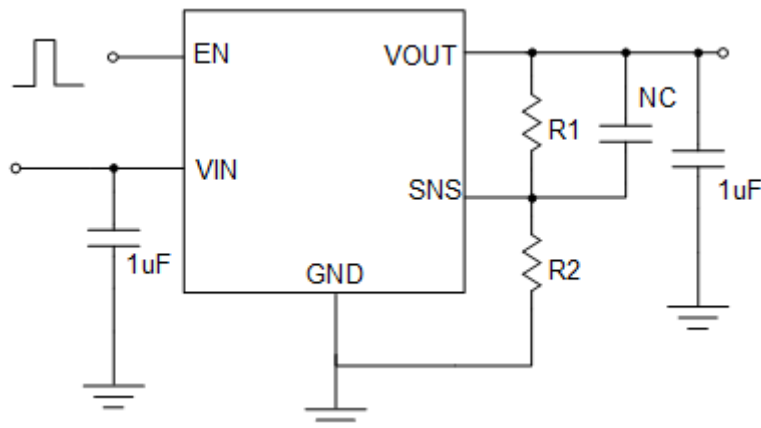
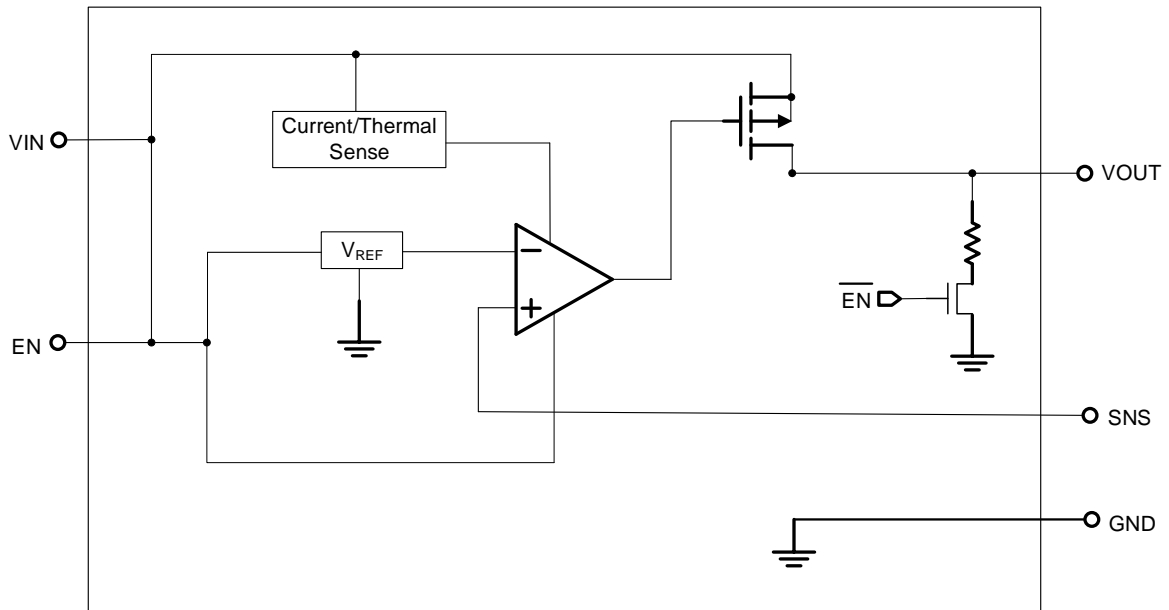


Figure 1 : Adjustable output voltage LDO application circuit

Function Block Diagram



Absolute Maximum Ratings (Note 1)

VIN to GND	-----	-0.3V to 6.5V
VOUT, EN, SNS to GND	-----	-0.3V to 6V
VOUT to VIN	-----	-6V to 0.3V
Package Thermal Resistance (Note 2)		
SOT-23-5, θ_{JA}	-----	200 °C /W
Lead Temperature (Soldering, 10 sec.)	-----	260 °C
Junction Temperature	-----	150 °C
Storage Temperature Range	-----	-60 °C to 150 °C
ESD Susceptibility		
HBM	-----	2KV
MM	-----	200V
CDM	-----	2KV

Recommended Operating Conditions

Input Voltage VIN	-----	1.2V to 5.5V
Junction Temperature Range	-----	-40 °C to 125 °C
Ambient Temperature Range	-----	-40 °C to 85 °C

Electrical Characteristics

($V_{IN} = 5V$, $V_{EN} = 5V$ $T_A = 25^\circ C$ unless otherwise specified)

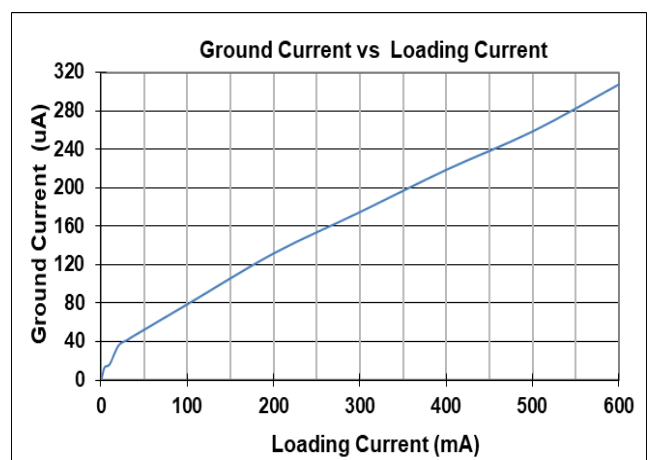
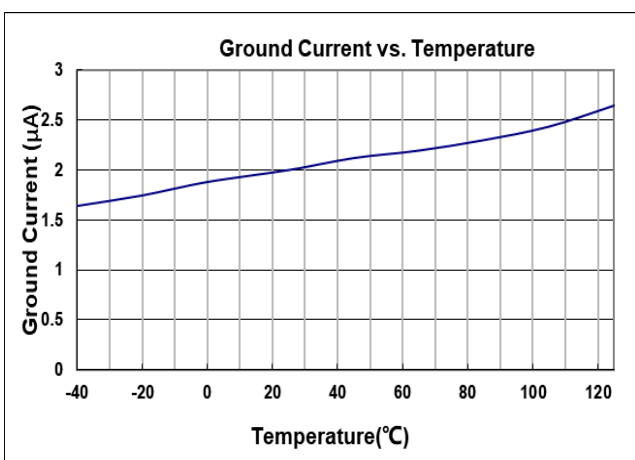
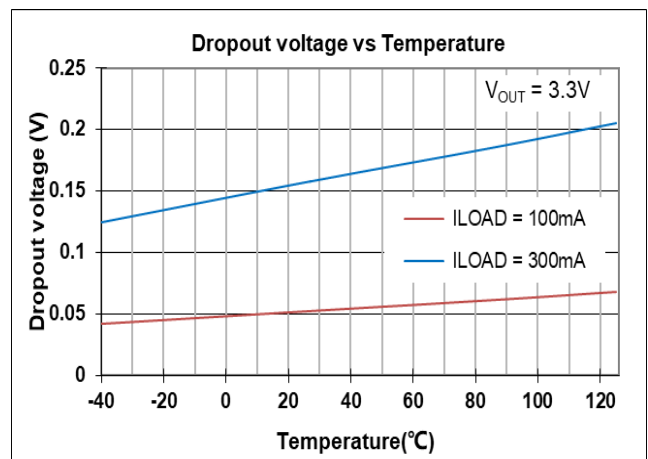
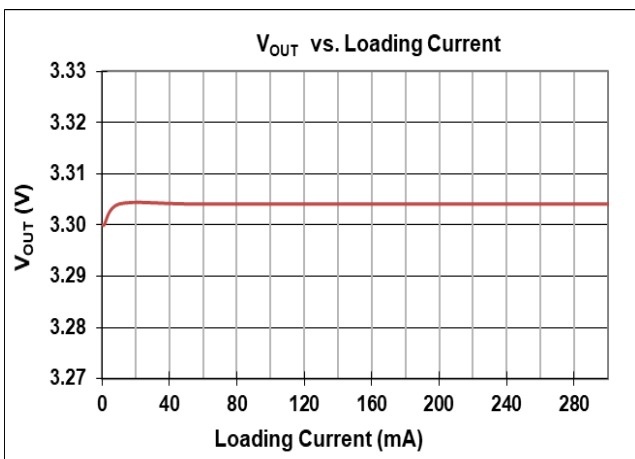
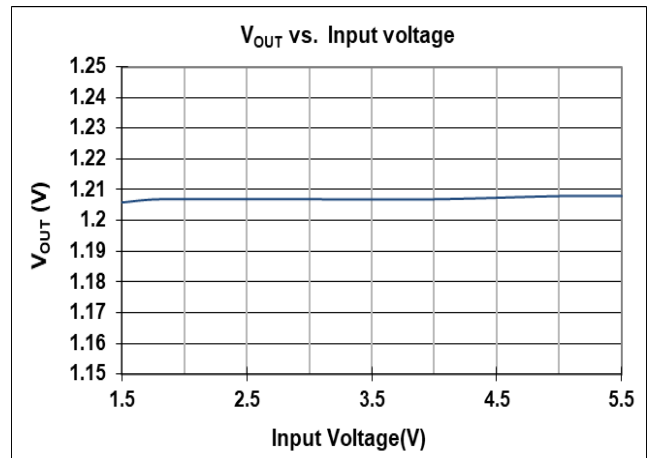
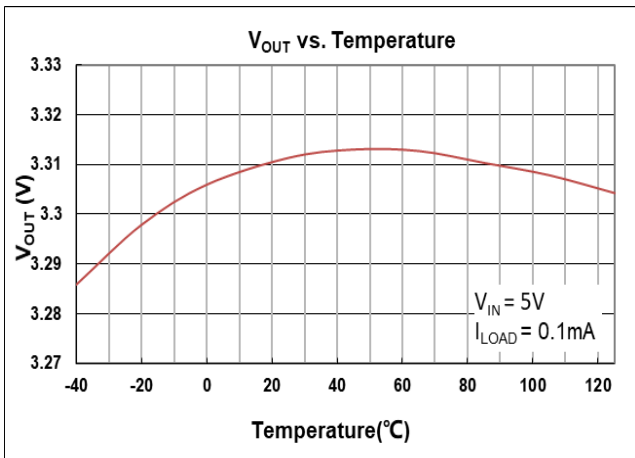
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit	
Supply Voltage	V_{IN}		1.2	--	5.5	V	
DC Output Voltage Accuracy	V_{SNS}	$I_{LOAD} = 0.1mA$	1.176	1.2	1.224	V	
SNS Input Current	I_{SNS}	$SNS = V_{OUT}$		0.7		μA	
Dropout Voltage ($I_{LOAD} = 600mA$) (Note 3)	V_{DROP_3V}	$V_{OUT} \geq 3V$		0.32		V	
	$V_{DROP_2.8V}$	$V_{OUT} = 2.8V$		0.36			
	$V_{DROP_2.5V}$	$V_{OUT} = 2.5V$		0.36			
	$V_{DROP_1.8V}$	$V_{OUT} = 1.8V$		0.57			
	$V_{DROP_1.5V}$	$V_{OUT} = 1.5V$		0.71			
	$V_{DROP_1.2V}$	$V_{OUT} = 1.2V$		0.8			
Ground Current	I_Q	$I_{LOAD} = 0mA$		2		μA	
Shutdown Ground Current	I_{SD}	$V_{EN} = 0V$,		0.01	0.5	μA	
V_{OUT} Shutdown Leakage Current	I_{LEAK}	$V_{OUT} = 0V$		0.01	0.5		
Enable Threshold Voltage	V_{IH}	EN Rising			2	V	
	V_{IL}	EN Falling	0.6				
EN Input Current	I_{EN}	$V_{EN} = 5V$		10	100	nA	
Line Regulation	$\Delta LINE$	$I_{LOAD} = 30mA$, $1.5V \leq V_{IN} \leq 5.5V$ or $(V_{OUT} + 0.2V) \leq V_{IN} \leq 5.5V$		0.2		%	
Load Regulation	$\Delta LOAD$	$10mA \leq I_{LOAD} \leq 0.3A$		0.2		%	
Output Current Limit	I_{LIM}	$V_{OUT} = 0$	601	1100		mA	
Power Supply Rejection Ratio ($I_{LOAD} = 5mA$)	PSRR	$V_{OUT} = 1.2V$, $V_{IN} = 2V$	$f = 100Hz$	--	80	--	dB
			$f = 1kHz$	--	75	--	
Output Voltage Noise (BW = 10Hz to 100kHz, $C_{OUT} = 1\mu F$.)	Noise	$V_{IN} = 3.5V$ $I_{LOAD} = 0.1A$	$V_{OUT} = 0.9V$	--	40	--	μV_{RMS}
			$V_{OUT} = 2.8V$	--	50	--	
Thermal Shutdown Temperature	T_{SD}	$I_{LOAD} = 10mA$		--	155	--	$^\circ C$
Thermal Shutdown Hysteresis	ΔT_{SD}			--	15	--	$^\circ C$
Discharge Resistance		$EN = 0V$, $V_{OUT} = 0.1V$		--	100	--	Ω

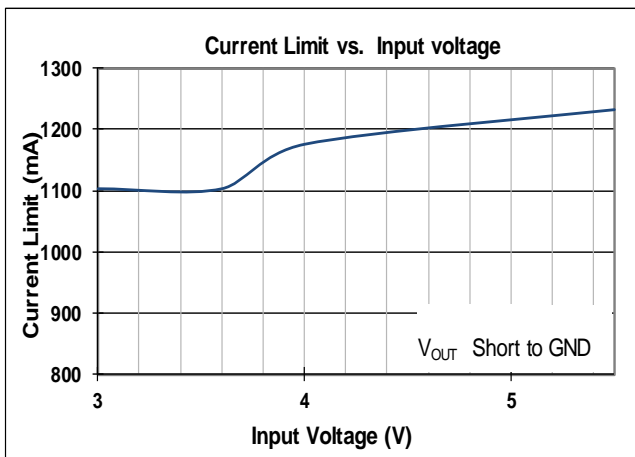
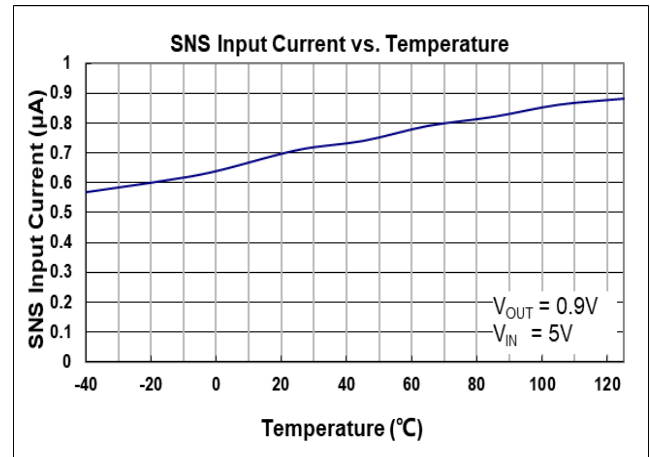
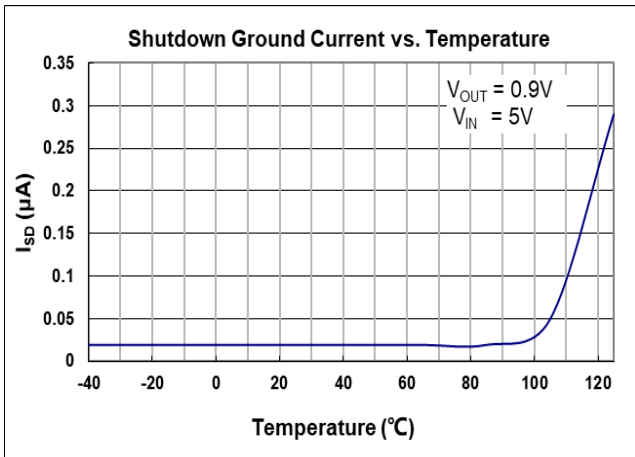
Note 1. Stresses beyond those listed “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Note 2. θ_{JA} is measured at $T_A = 25^\circ\text{C}$ on a DSTECH EVB board.

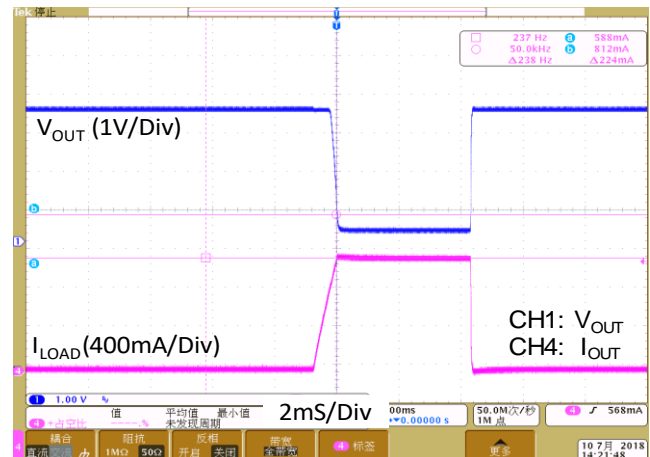
Note 3. $V_{\text{DROP}} = V_{\text{IN}} - V_{\text{OUT}}$ when the V_{OUT} is 98% of its target value.

Typical Characteristics

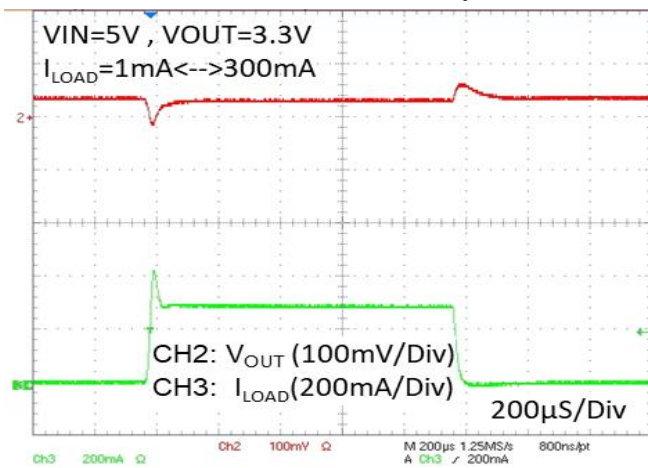




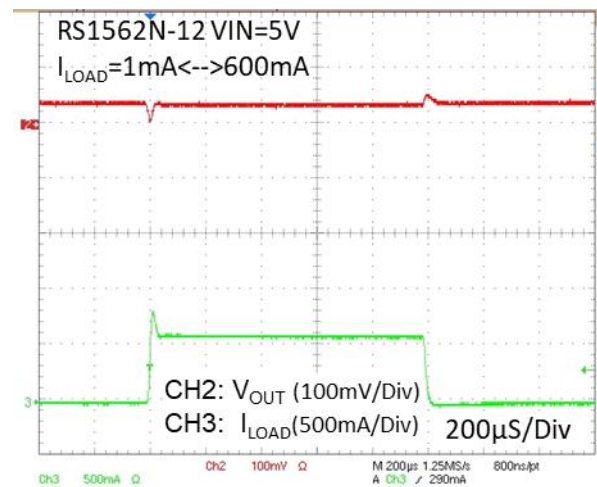
Current Limit Response



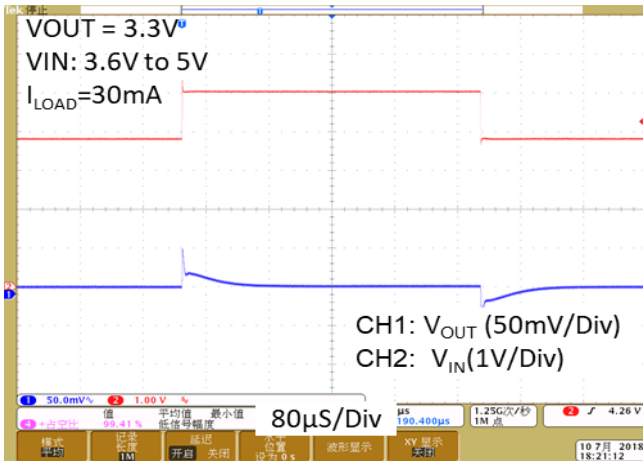
Load Transient Response I



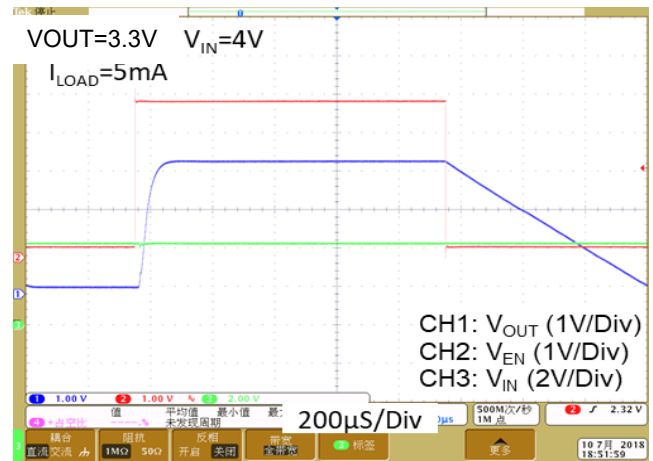
Load Transient Response II



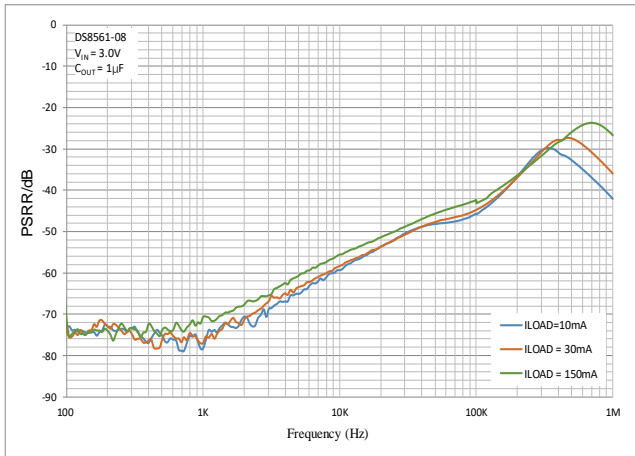
Line Transient Response



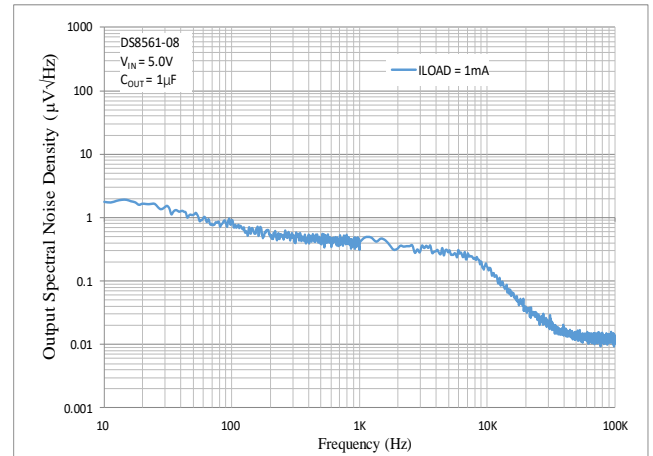
V_{OUT} Turn On/Off by EN



PSRR vs. Frequency



Noise Density Spectrum



Application Guideline

Input and Output Capacitor Requirements

The external input and output capacitors of RS1562N series must be properly selected for stability and performance. Use a 1 μ F or larger input capacitor and place it close to the IC's VIN and GND pins. Any output capacitor meeting the minimum 1m Ω ESR (Equivalent Series Resistance) and effective capacitance between 1 μ F and 22 μ F requirement may be used. Place the output capacitor close to the IC's VOUT and GND pins. Increasing capacitance and decreasing ESR can improve the circuit's PSRR and line transient response.

Current Limit

The RS1562N series contain the current limiter of output power transistor, which monitors and controls the transistor, limiting the output current to 1100mA (typical).

The output can be shorted to ground indefinitely without damaging the part.

Dropout Voltage

The RS1562N series use a PMOS pass transistor to achieve low dropout. When (VIN – VOUT) is less than the dropout voltage (VDROP), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the RDS(ON) of the PMOS pass element. VDROP scales approximately with the output current because the PMOS device behaves as a resistor in dropout condition.

As any linear regulator, PSRR and transient response are degraded as (VIN – VOUT) approaches dropout condition.

Adjustable Output Voltage Application

The RS1562N by SNS pin also can work as an adjustable output voltage LDO. Figure 1 gives the connections for the adjustable output voltage application. The resistor divider from VOUT to SNS sets the output voltage when in regulation.

The voltage on the SNS pin sets the output voltage and is determined by the values of R1 and R2. To keep a good temperature coefficient of output voltage, the values of R1 and R2 should be selected carefully to ignore the temperature effect of input current at the SNS pin. A current greater than 50 μ A in the resistor divider is recommended to meet the above requirement. The adjustable output voltage can be calculated using the formula given in equation 1:

$$V_{OUT} = \frac{R1+R2}{R2} \times V_{SNS} \quad (1)$$

where VSNS is determined by the output voltage selections in the ordering information of RS1562N-12.

The minimum recommended 50 μ A in the resistor divider makes the application no longer a 2 μ A low quiescent LDO.

OTP (Over Temperature Protection)

The over temperature protection function of RS1562N series will turn off the P-MOSFET when the junction temperature exceeds 155 $^{\circ}$ C (typ.). Once the junction temperature cools down by approximately 15 $^{\circ}$ C, the regulator will automatically resume operation.

Thermal Application

For continuous operation, do not exceed the absolute maximum junction temperature. The maximum power dissipation depends on the thermal resistance of the IC package, PCB layout, rate of surrounding airflow, and difference between junction and ambient temperature. The maximum power dissipation can be calculated as below:

$T_A=25^{\circ}\text{C}$, DS-Tech PCB,

The max PD (Max) = $(125^{\circ}\text{C} - 25^{\circ}\text{C}) / (200^{\circ}\text{C}/\text{W}) = 0.5\text{W}$ for SOT-23-5 package.

Power dissipation (PD) is equal to the product of the output current and the voltage drop across the output pass element, as shown in the equation below:

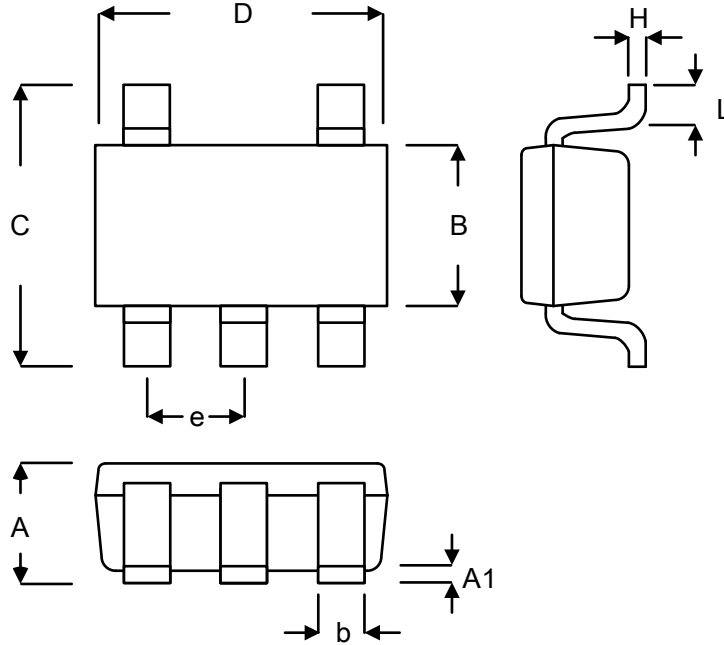
$$\text{PD} = (\text{VIN} - \text{VOUT}) \times \text{IOUT}$$

Layout Consideration

By placing input and output capacitors on the same side of the PCB as the LDO, and placing them as close as is practical to the package can achieve the best performance. The ground connections for input and output capacitors must be back to the RS1562N ground pin using as wide and as short of a copper trace as is practical.

Connections using long trace lengths, narrow trace widths, and/or connections through via must be avoided. These add parasitic inductances and resistance that results in worse performance especially during transient conditions.

Package Information:



Symbol	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	0.889	1.295	0.035	0.051
A1	0.000	0.152	0.000	0.006
B	1.397	1.803	0.055	0.071
b	0.250	0.560	0.010	0.022
C	2.591	2.997	0.102	0.118
D	2.692	3.099	0.106	0.122
e	0.838	1.041	0.033	0.041
H	0.080	0.254	0.003	0.010
L	0.300	0.610	0.012	0.024

SOT-23-5L